



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of: **Yasuhiko NOMURA et al.**

Serial No.: **09/666,553**

Filed: **September 21, 2000**

Group Art Unit: **2828**

Examiner: **Quyen Phan Leung**

FOR: **SEMICONDUCTOR LIGHT EMITTING DEVICE**

**AMENDMENT UNDER 37 C.F.R. §1.111**

Commissioner for Patents  
Washington, D.C. 20231

Date: **August 5, 2002**

Sir:

In response to the Office Action dated March 5, 2002, please amend the above-identified application as follows:

**IN THE CLAIMS:**

**Please amend claims 17-20 as follows:**

*Sheet 01*  
17. (Amended) A semiconductor light emitting device comprising:

an emission layer composed of a nitride-based semiconductor;

a cladding layer, formed on said emission layer, composed of a nitride-based semiconductor

having a flat portion and a projection portion located on said flat portion; and

a layer of nitride-based semiconductor formed on said projection portion, wherein

*A*  
said projection portion of said cladding layer and said layer formed on said projection portion form a ridge portion, and

said ridge portion has a step formed between said projection portion of said cladding layer and said layer formed on said projection portion;

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